

Is Now Part of



# **ON Semiconductor**®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor dates sheds, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheds and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use on similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any lange of the applicatio customer's to unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the

December 2013



SEMICONDUCTOR®

## IRL640A N-Channel Logic Level A-FET 200 V, 18 A, 180 mΩ

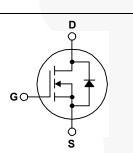
#### Description

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar, DMOS technology. This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for high efficiency switching DC/DC converters, switch mode power supplies, DC-AC converters for uninterrupted power supply and motor control.

#### Features

- 18 A, 200 V,  $R_{DS(on)}$  = 180 m $\Omega$  @ V<sub>GS</sub> = 5 V
- Low Gate Charge (Typ. 40 nC)
- Low Crss (Typ. 95 pF)
- Fast Switching
- 100% Avalanche Tested
- Improved dv/dt Capability
- Logic-Level Gate Drive





## Absolute Maximum Ratings

Symbol	Characteristic	Value	Units	
V <sub>DSS</sub>	Drain-to-Source Voltage	200	V	
I	Continuous Drain Current (T <sub>C</sub> =25°C)	18	_	
Ι <sub>D</sub>	Continuous Drain Current (T <sub>c</sub> =100°C)	11.4	A	
I <sub>DM</sub>	Drain Current-Pulsed (1)	63	А	
V <sub>GS</sub>	Gate-to-Source Voltage	±20	V	
E <sub>AS</sub>	Single Pulsed Avalanche Energy (2)	64	mJ	
I <sub>AR</sub>	Avalanche Current (1)	18	A	
E <sub>AR</sub>	Repetitive Avalanche Energy (1)	11	mJ	
dv/dt	Peak Diode Recovery dv/dt (3)	5	V/ns	
	Total Power Dissipation (T <sub>c</sub> =25°C)	110	W	
$P_D$	Linear Derating Factor	0.88	W/°C	
	Operating Junction and	55 1 150	C	
$T_J$ , $T_STG$	Storage Temperature Range	- 55 to +150		
-	Maximum Lead Temp. for Soldering	000	°C	
TL	Purposes, 1/8. from case for 5-seconds	300		

#### **Thermal Resistance**

Symbol	Characteristic	Тур.	Max.	Units
$R_{ extsf{ heta}JC}$	Junction-to-Case		1.14	
$R_{ extsf{ heta}CS}$	Case-to-Sink	0.5		°C/W
$R_{ extsf{ heta}JA}$	Junction-to-Ambient		62.5	

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity	
IRL640A	IRL640A	TO-220	Tube	N/A	N/A	50 units	

#### Electrical Characteristics (T<sub>c</sub>=25 °C unless otherwise specified)

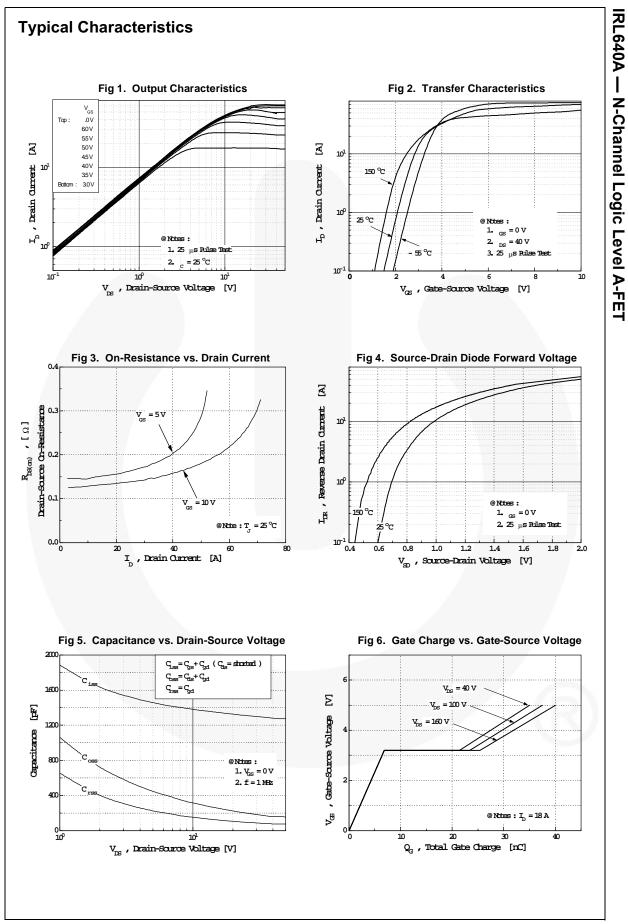
Symbol	Characteristic		Тур.	Max.	Units	Test Condition	
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage				V	V <sub>GS</sub> =0V,I <sub>D</sub> =250μA	
$\Delta \text{BV} / \Delta \text{T}_{\text{J}}$	Breakdown Voltage Temp. Coeff.		0.17		V/∘C	I <sub>D</sub> =250μA <b>See Fig 7</b>	
V <sub>GS(th)</sub>	Gate Threshold Voltage	1.0		2.0	V	V <sub>DS</sub> =5V,I <sub>D</sub> =250μA	
	Gate-Source Leakage, Forward			100	nA	V <sub>GS</sub> =20V	
I <sub>GSS</sub>	Gate-Source Leakage, Reverse			-100	IIA	V <sub>GS</sub> =-20V	
				10		V <sub>DS</sub> =200V	
I <sub>DSS</sub>	Drain-to-Source Leakage Current			100	μA	V <sub>DS</sub> =160V,T <sub>C</sub> =125°C	
R <sub>DS(on)</sub>	Static Drain-Source On-State Resistance			0.18	Ω	$V_{GS}=5V, I_{D}=9A \qquad (4)$	
9 <sub>fs</sub>	Forward Transconductance		13.3		Ω	$V_{DS}$ =40V,I <sub>D</sub> =9A (4)	
C <sub>iss</sub>	Input Capacitance		1310	1705			
C <sub>oss</sub>	Output Capacitance		200	250	рF	V <sub>GS</sub> =0V,V <sub>DS</sub> =25V,f =1MHz	
C <sub>rss</sub>	Reverse Transfer Capacitance		95	120		See Fig 5	
t <sub>d(on)</sub>	Turn-On Delay Time		11	30		V 100V/1 10A	
t <sub>r</sub>	Rise Time Turn-Off Delay Time		8	25	ns	$V_{DD}=100V,I_{D}=18A,$ $R_{G}=4.6\Omega$	
t <sub>d(off)</sub>			46	100			
t <sub>f</sub>	Fall Time		15	40		<b>See Fig 13</b> (4) (5)	
Qg	Q <sub>gs</sub> Gate-Source Charge		40	56		V <sub>DS</sub> =160V,V <sub>GS</sub> =5V,	
$Q_gs$			6.8		nC	I <sub>D</sub> =18A	
$Q_{gd}$			18.6			See Fig 6 & Fig 12 (4) (5)	

## Source-Drain Diode Ratings and Characteristics

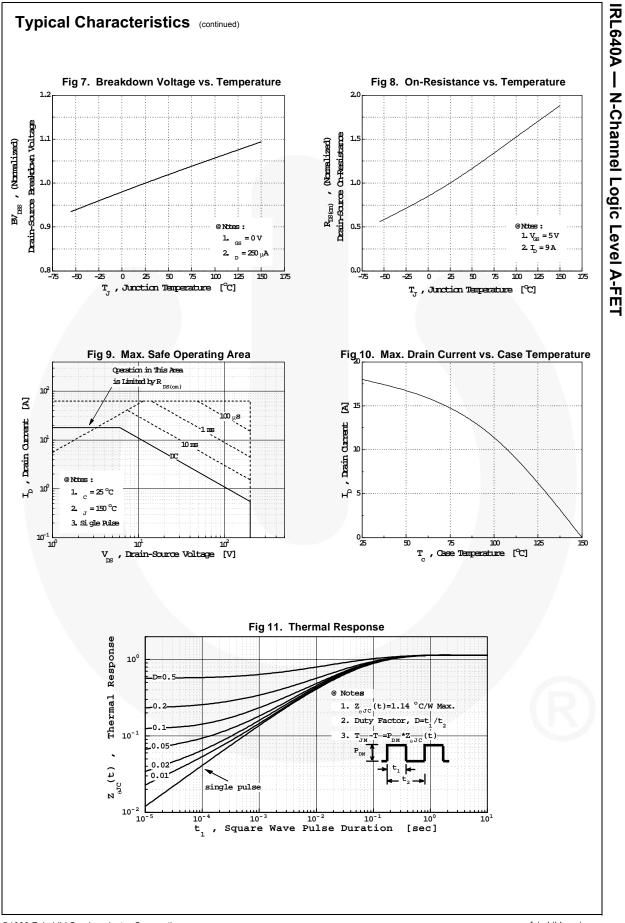
Symbol	Characteristic		Тур.	Max.	Units	Test Condition
ا <sub>s</sub>	Continuous Source Current18Pulsed-Source Current(1)63			Integral reverse pn-diode		
I <sub>SM</sub>				63	A	in the MOSFET
V <sub>SD</sub>	Diode Forward Voltage (4)			1.5	V	T <sub>J</sub> =25°C,I <sub>S</sub> =18A,V <sub>GS</sub> =0V
t <sub>rr</sub>	Reverse Recovery Time		224		ns	T <sub>J</sub> =25°C,I <sub>F</sub> =18A
Q <sub>rr</sub>	Reverse Recovery Charge		1.55		μC	di <sub>F</sub> /dt=100A/µs (4)

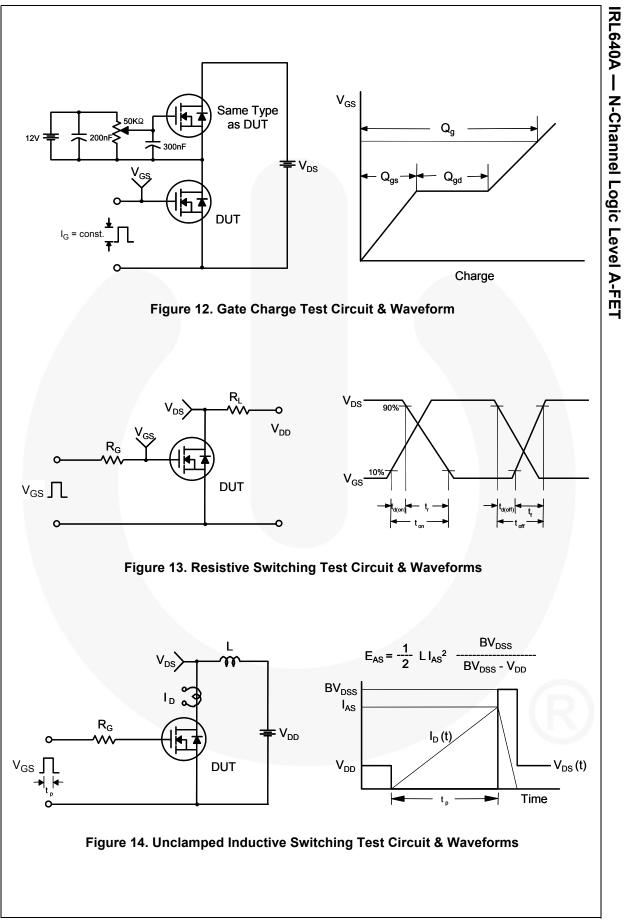
#### Notes:

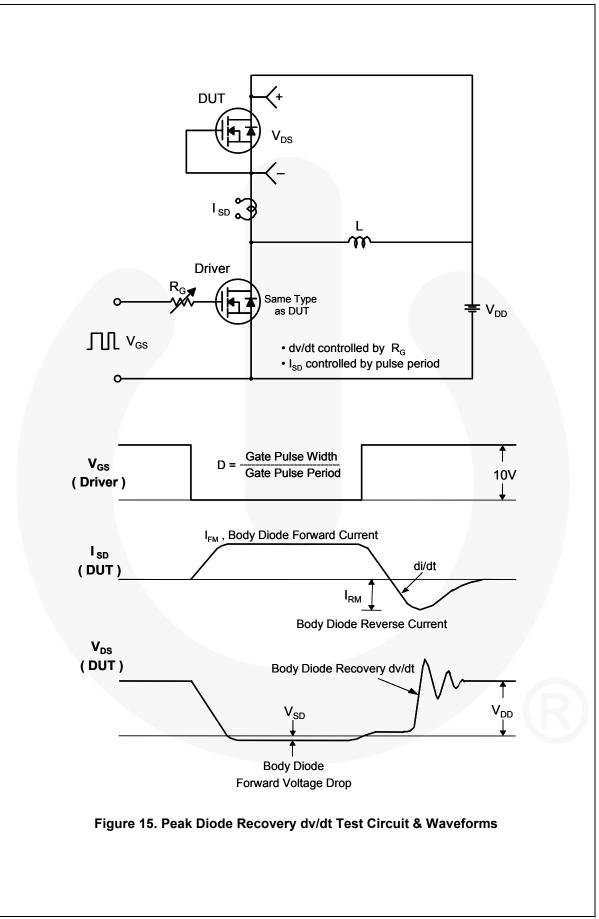
- (1) Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature
- (2) L=0.3mH, I<sub>AS</sub>=18A, V<sub>DD</sub>=50V, R<sub>G</sub>=27 $\Omega$ , Starting T<sub>J</sub>=25°C
- (3)  $I_{SD} \le 18A$ , di/dt  $\le 260A/\mu s$ ,  $V_{DD} \le BV_{DSS}$ , Starting  $T_J = 25^{\circ}C$ (4) Pulse Test: Pulse Width = 250 $\mu s$ , Duty Cycle  $\le 2\%$
- (5) Essentially Independent of Operating Temperature

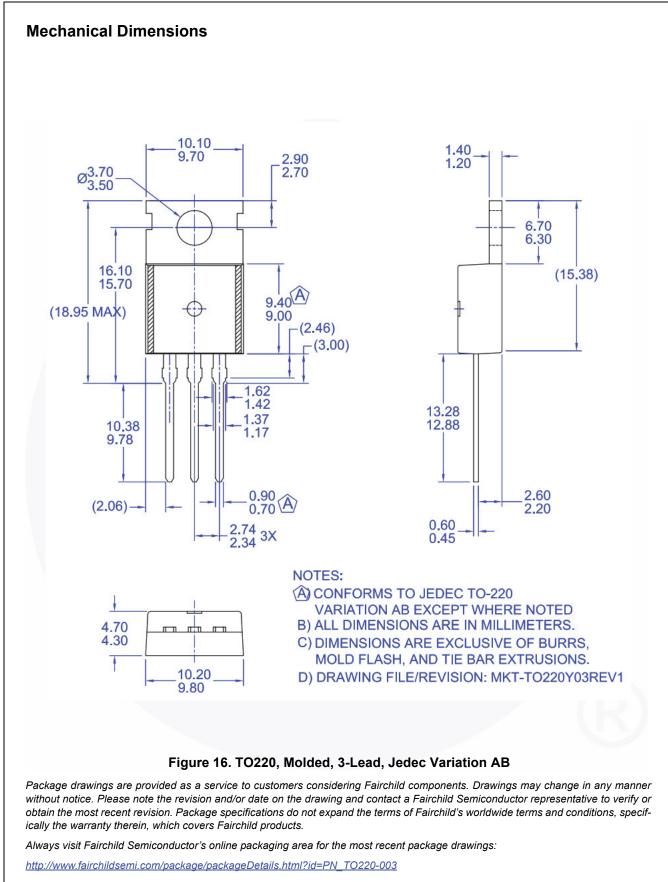


©1999 Fairchild Semiconductor Corporation IRL640A Rev. C0











Datasneet identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
		Rev. 166

**RL640A** 

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC